QUAD OPERATIONAL AMPLIFIERS

The KA224 series consists of four independent, high gain, internally frequency compensated operational amplifiers which were designed specifically to operate from a single power supply over a wide voltage range.

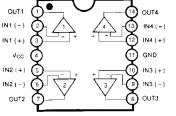
Operation from split power supplies is also possible so long as the difference between the two supplies is 3 volts to 32 volts.

Application areas include transducer amplifier, DC gain blocks and all the conventional OP amp circuits which now can be easily implemented in single power supply systems.

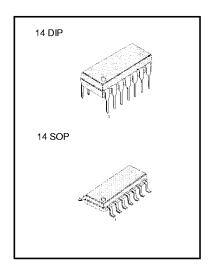
FEATURES

- Internally frequency compensated for unity gain
- Large DC voltage gain: 100dB
- Wide power supply range: KA224/A, KA324/A: 3V 32V (or± 1.5 ~ 15V) KA2902: 3V~26V (or± 1.5V ~ 13V)
- Input common-mode voltage range includes ground
- Large output voltage swing: 0V DC to V_{CC}-1.5V DC
- Power drain suitable for battery operation.



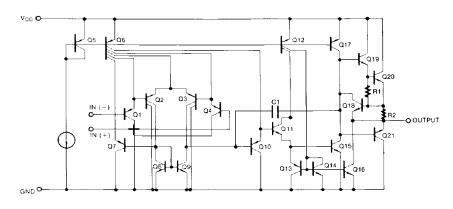


SCHEMATIC DIAGRAM (One Section Only)



ORDERING INFORMATION

Device	Package	Operating Temperature
KA324	14 DIP	
KA324A		0 ~ + 70 ℃
KA324D	14 SOP	0~+700
KA324AD	14 SUF	
KA224	14 DIP	
KA224A		-25 ~ +85℃
KA224D	14 SOP	-23 ** +03 6
KA224AD	14 306	
KA2902	14 DIP	-40 ~ + 85 ℃
KA2902D	14 SOP	-40 ** + 65 (





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ABSOLUTE MAXIMUM RATINGS

Characteristic	Symbol	KA224/KA224A	KA324/KA324A	KA2902	Unit
Power Supply Voltage	Vcc	± 18 or 32	± 18 or 32	± 13 or 26	V
Differential Input Voltage	VI(DIFF)	32	32	26	v
Input Voltage	Vi	-0.3 to + 32	-0.3 to +32	-0.3 to +26	v
Output Short Circuit to GND		Continuous	Continuous	Continuous	
V _{CC} ≤ 15V T _A =25 ℃ (One Amp)		Continuous	Continuous	Continuous	
Power Dissipation	PD	570	570	570	mW
Operating Temperature Range	Topr	-25 ~ +85	0 ~ + 70	-40 ~ + 85	C
Storage Temperature Range	T _{STG}	-65 ~ + 150	-65 ~ + 150	-65 ~ + 150	ĉ

ELECTRICAL CHARACTERISTICS

(V_{CC}=5.0V, V_{EE}=GND, T_{A}=25\,^{\circ}\mathrm{C} , unless otherwise specified)

	Sumbol	Symbol Test Conditions		1	KA224			KA324			(A290		
Characteristic	Symbol	Test Condition	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit	
Input Offset Voltage	V _{IO}	$V_{CM} = 0V$ to V_{CC} $V_{O(P)} = 1.4V$, Rs			1.5	5.0		1.5	7.0		1.5	7.0	mV
Input Offset Current	l _{io}				2.0	30		3.0	50		3.0	50	nA
Input Bias Current	IBIAS				40	150		40	250		40	250	nA
Input Common-Mode Voltage Range	V _{I(R)}	V _{cc} = 30V (V _{cc} = 26V for K		0		V _{cc} -1.5	0	V _{cc} -1.5		0		V _{cc} -1.5	v
		$R_L = ,V_{CC} = 30V$	(all Amps)		1.0	3		1.0	3		1.0	3	mA
Supply Current	lcc	$R_{L} = ,V_{CC} = 5V ($ $(V_{CC} = 26V \text{ for } K)$			0.7	1.2		0.7	1.2		0.7	1.2	mA
Large Signal Voltage Gain	Gv	V _{CC} = 15V, R _L ≥ V _{O(P)} = 1V to		50	100		25	100			100		V/mV
		$V_{CC} = 30V$	RL = 2K0	26			26			22			V
Output Voltage Swing	V _{O(H)}	V _{cc} =26V for 2902	R _L = 10KΩ	27	28		27	28		23	24		V
	V _{O(L)}	$V_{CC} = 5V, R_L^2 = 10K\Omega$			5	20		5	20		5	100	mV
Common-Mode Rejection Ratio	CMRR			70	85		65	75		50	75		dB
Power Supply Rejection Ratio	PSRR			65	100		65	100		50	100		dB
Channel Separation	CS	f = 1KHz to 20)KHz		120			120			120		dB
Short Circuit to GND	lsc				40	60		40	60		40	60	mA
	ISOURCE	$V_{l(+)} = 1V, V_{l(-)}$ $V_{CC} = 15V, V_{O(l)}$		20	40		20	40		20	40		mA
Output Current		$V_{I(+)} = 0V, V_{I(-)} = 1V$ $V_{CC} = 15V, V_{O(P)} = 2V$		10	13		10	13		10	13		mA
	Isink	$V_{I(+)} = 0V, V_{I(-)} = 1V$ $V_{CC} = 15V, V_{O(R)} = 200mV$		12	45		12	45					μΑ
Differential Input Voltage	V _{I(DIFF)}					Vcc			Vcc			V_{cc}	V



SEMICONDUCTOR™

KA224/A, KA324/A, KA2902

QUAD OPERATIONAL AMPLIFIER

ELECTRICAL CHARACTERISTICS

 $(V_{CC} = 5.0V, V_{EE} = GND, unless otherwise specified)$ The following specification apply over the range of -25°C≤ T_A≤ + 85°C for the KA224; and the 0°C≤ T_A≤ +70°C for the KA324 ; and the - 40°C≤ T_A≤ +85°C for the KA2902

Characteristic	Symbol	ymbol Test Conditions			KA224			KA324			KA2902		
Characteristic	Symbol			Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
Input Offset Voltage	V _{IO}	$\label{eq:ViCM} \begin{split} V_{\text{ICM}} &= 0V \text{ to } V_{\text{CC}} = \\ V_{\text{O}(P)} &= 1.4V, \ R_{\text{S}} = 0 \end{split}$				7.0			9.0			10.0	mV
Input Offset Voltage Drift	Δ V _{IO} /Δ T				7.0			7.0			7.0		μ ν/ ℃
Input Offset Current	lio					100			150			200	nA
Input Offset Current Drift	Δ Ι _{ΙΟ} /Δ Τ				10			10			10		p A /℃
Input Bias Current	IBIAS					300			500			500	nA
Input Common-Mode Voltage Range	V _{IC(R)}	$V_{CC} = 30V$ ($V_{CC} = 26V$ for KA2	902)	0		V _{cc} -2.0	0		V _{cc} -2.0	0		V _{cc} -2.0	v
Large Signal Voltage Gain	Gv	V _{CC} = 15V, R _L ≥ 2.0 V _{O(P)} = 1V to 11V	DKΩ	25			15			15			V/mV
	N	$V_{CC} = 30V$	$R_L = 2K\Omega$	26			26			22			V
Output Voltage Swing	V _{O(H)}	V _{cc} =26V for 2902	R∟ = 10KΩ	27	28		27	28		23	24		V
	V _{O(L)}	$V_{CC}=5V,\ R_L\!\!\geq\ 10K$	2		5	20		5	20		5	100	mV
	ISOURCE			10	20		10	20		10	20		mA
Output Current	Isink			10	13		5	8		5	8		mA
Differential Input Voltage	VI(DIFS)					Vcc			v_{cc}			v_{cc}	V



ELECTRICAL CHARACTERISTICS

(V_{CC}{=}50V, V_{EE}{\,=\,}GND, T_{A}{=}25\,^\circ\!\!\mathrm{C} , unless otherwise specified)

Characteristic	Symbol	Test Canditions	k	(A 224	A		KA324	Unit	
Characteristic	Symbol	Test Conditions		Тур	Max	Min	Тур	Max	Unit
Input Offset Voltage	V _{IO}	$V_{CM} = 0V$ to $V_{CC} = 1.5V$ $V_{O(P)} = 1.4V$, $R_S = 0$		1.0	3.0		1.5	3.0	mV
Input Offset Current	lio			2	15		3.0	30	nA
Input Bias Current	BIAS			40	80		40	100	nA
Input Common-Mode Voltage Range	V _{I(R)}	$V_{CC} = 30V$	0		V _{cc} -1.5	0		V _{cc} -1.5	v
Supply Current (All Amps)	lcc	$V_{CC} = 30V$		1.5	3		1.5	3	mA
Supply Current (All Amps)	ICC	$V_{CC} = 5V$		0.7	1.2		0.7	1.2	mA
Large Signal Voltage Gain	Gv	V _{CC} = 15V, R _L ≥ 2KΩ V _{O(P)} = 1V to 11V	50	100		25	100		V/mV
	V _{O(H)}	V _{CC} = 30V R _L = 2KΩ	26			26			V
Output Voltage Swing		$V_{CC} = 26V$ for 2902 $R_L = 10K\Omega$	27	28		27	28		V
	V _{O(L)}	V _{CC} = 5V, R _L ≥ 10KΩ		5	20		5	20	mV
Common-Mode Rejection Ratio	CMRR		70	85		65	85		dB
Power Supply Rejection Ratio	PSRR		65	100		65	100		dB
Channel Separation	CS	f = 1KHz to 20KHz		120			120		dB
Short Circuit to GND	lsc			40	60		40	60	mA
	ISOURCE	$V_{I(+)} = 1V, V_{I(-)} = 0V$ $V_{CC} = 15V$	20	40		20	40		mA
Output Current	Isink		10	20		10	20		mA
			12	50		12	50		μΑ
Differential Input Voltage	V _{I(DIFF)}				V_{CC}			Vcc	V

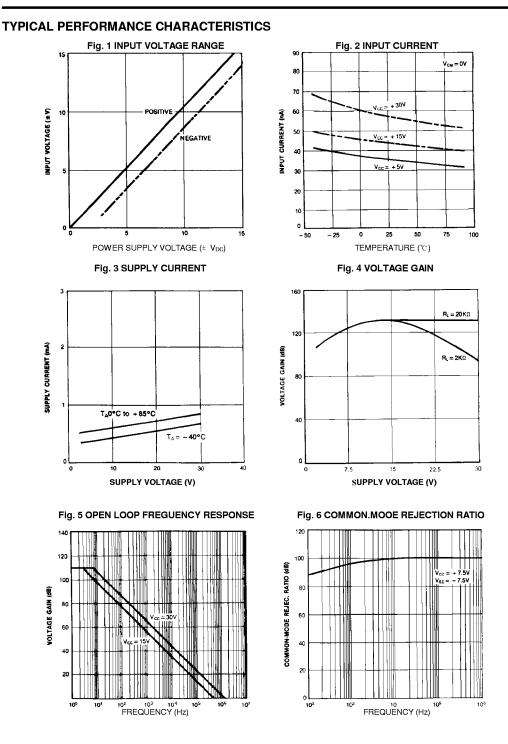


ELECTRICAL CHARACTERISTICS

 $(V_{CC} = 5.0V, V_{EE} = GND$, unless otherwise specified) The following specification apply over the range of -25 °C $T_A \le +85$ °C for the KA224A; and the 0 °C $\le T_A \le +70$ °C for the KA324A

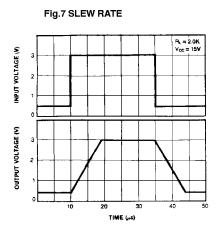
Characteristic		Symbol Test Conditions		ŀ	KA224A			KA324	11	
Characteristic	Symbol			Min	Тур	Max	Min	Тур	Max	Unit
Input Offset Voltage	V _{IO}	$V_{CM} = 0V$ to $V_{CC} = 1.5V$ $V_{Q(P)} = 1.4V, R_S = 0\Omega$				4.0			5.0	mV
Input Offset Voltage Drift	Δ V _{IO} /Δ Τ				7.0	20		7.0	30	μ V /℃
Input Offset Current	lio					30			75	nA
Input Offset Current Drift	ΔΙιο/ΔΤ				10	200		10	300	p A /℃
Input Bias Current	IBIAS				40	100		40	200	nA
Input Common-Mode Voltage Range	V _{I(R)}	$V_{CC} = 30V$		0		V _{cc} -2.0	0		V _{cc} -2.0	v
Large Signal Voltage Gain	Gv	V _{cc} = 15V, I	R∟≥ 2.0KΩ	25			15			V/mV
		N 00V	R∟ = 2KΩ	26			26			
Output Voltage Swing	V _{O(P-P)}	$V_{CC} = 30V$	$R_L = 10 K\Omega$	27	28		27	28		V
		V _{cc} = 5V, F	V _{CC} = 5V, R _L ≤ 10KΩ		5	20		5	20	mA
	ISOURCE	$V_{I(+)} = 1V, V_{I(-)} = 0V$ $V_{CC} = 15V$		10	20		10	20		mA
Output Current	I _{SINK}	V _{I(+)} = 0V, V _{CC} =	.,	5	8		5	8		mA
Differential Input Voltage	VI(DIFF)					Vcc			Vcc	V





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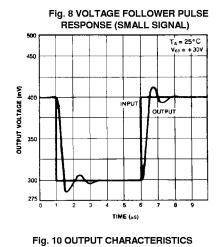
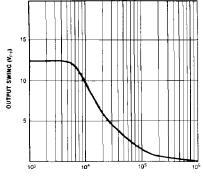
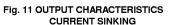
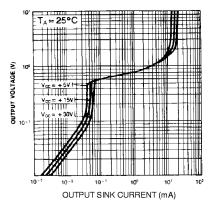


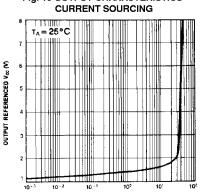
Fig. 9 LARGE SIGNAL FREQUECY RESPONSE



FREQUENCY (Hz)

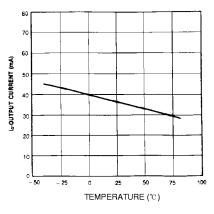






OUTPUT SOURCE CURRENT (mA)

Fig. 12 CURRENT LIMITING



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